

1. General description

Planar passivated high commutation three quadrant triac in a TO220F "full pack" plastic package. This triac is intended for use in motor control circuits where very high blocking voltage can occur. Rated junction temperature ($T_{j(max)}$ = 150 °C) without the aid of a snubber. It is used in applications where "high junction operating temperature capability" is required.

2. Features and benefits

- High junction operating temperature capability (T_{i(max)} = 150 °C)
- Full cycle AC conduction
- Over-voltage withstand capability to IEC 61000-4-5
- · Pin compatible with standard triacs
- Planar passivated for voltage ruggedness and reliability
- · Protective self turn-on capability for high energy transients
- Triggering in three quadrants only
- Very high immunity to IEC 61000-4-4 fast transient
- Package meets UL94V0 flammability requirement
- Package is RoHS compliant
- Package meets UL1557 isolation test requirement rated at 2500V RMS

3. Applications

- AC fan, pump and compressor controls
- · Highly inductive, resistive and safety loads
- · Large and small appliances (White Goods)
- · Reversing induction motor controls e.g. vertical axis washing machines
- Applications subject to high temperature (T_{i(max)} = 150 °C)

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _h ≤ 103°C; <u>Fig.1; Fig. 2; Fig. 3</u>	-	-	8	А
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p =20ms; <u>Fig. 4; Fig. 5</u>	-	-	80	А
		full sine wave; $T_{j(init)}$ = 25 °C; t_p =16.7ms	-	-	88	А
Tj	junction temperature		-	-	150	°C
Static ch	aracteristics	·				
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>	-	-	35	mA
		V_{D} = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	-	-	35	mA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; <u>Fig. 7</u>	-	-	35	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	40	mA
V _T	on-state voltage	I _T = 10 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.25	1.6	V
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit	200	-	-	V/µs
		V_{DM} = 536 V; T _j = 150 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit	100	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_{DM} = 400 \text{ V}; \text{ T}_{j} = 150 \text{ °C}; \text{ I}_{T(RMS)} = 8 \text{ A}; $ $dV_{com}/dt = 20 \text{ V}/\mu\text{s}; \text{ (snubberless condition); gate open circuit}$	1	-	-	A/ms

5. Pinning information

Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	T1	main terminal 1	mb	NI			
2	T2	main terminal 2		T2-T1			
3	G	gate		sym051			
mb	n.c.	mounting base; isolated					

6. Ordering information

Table 3. Ordering information								
Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	Name		method	quantity	version	issue date		
BTA208X-800CT	TO220F	BTA208X-800CTQ	Tube	50	SOT186A	14-Nov-2013		

7. Marking

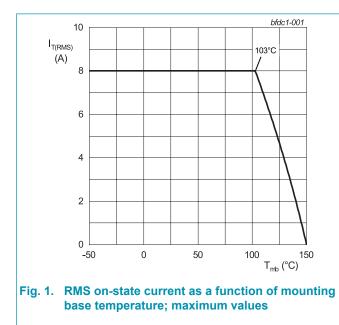
Т	able 4. Marking codes	
	Type number	Marking codes
	BTA208X-800CT	BTA208X-800CT

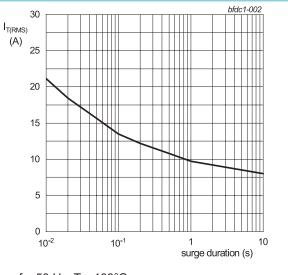
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

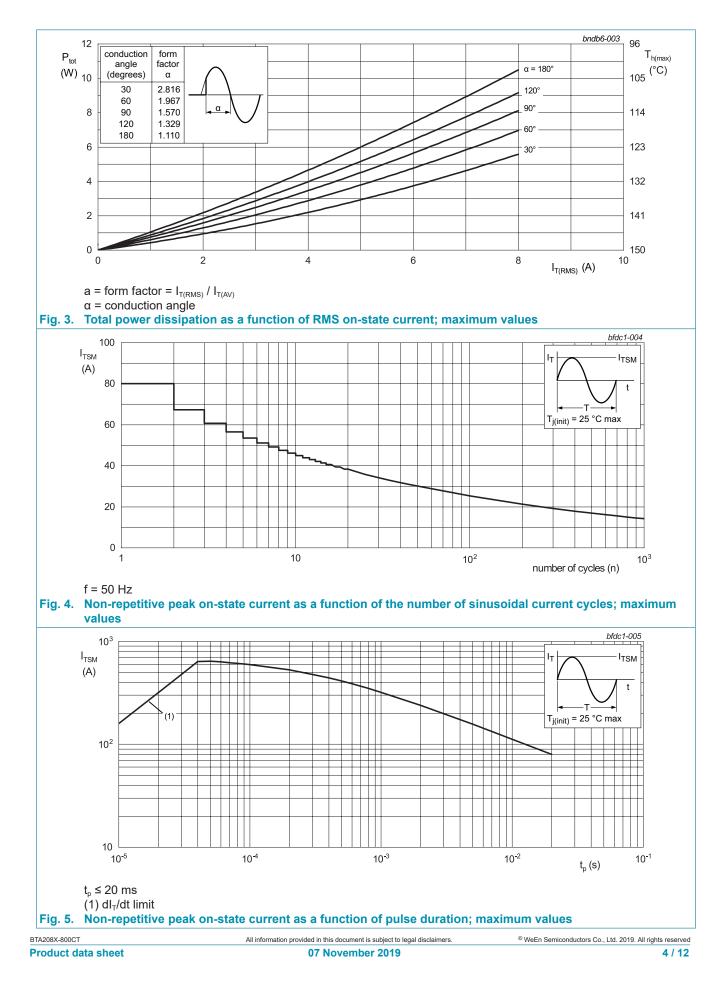
Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	800	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; T _{mb} ≤ 103°C; <u>Fig.1; Fig. 2</u> ; <u>Fig. 3</u>	-	8	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4;</u> <u>Fig. 5</u>	-	80	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	88	А
l ² t	I ² t for fusing	t_P = 10 ms; sine wave pulse	-	30	A ² s
dl _T /dt	rate of rise of on-state current	I _G = 70 mA	-	150	A/µs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C







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9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	full cycle; <u>Fig. 6</u>	-	-	4.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	-	60	-	K/W



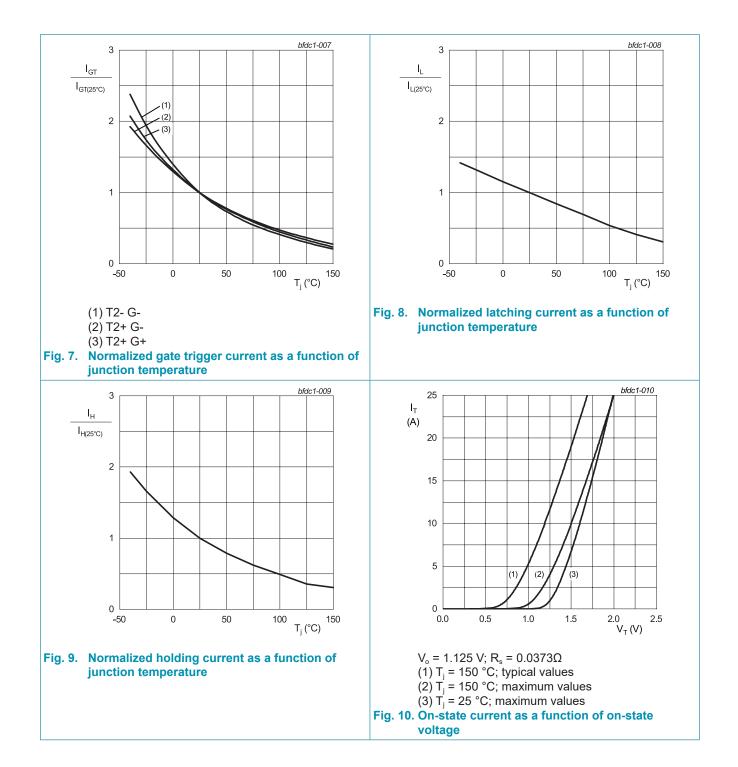
10. Isolation characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{\text{isol}(\text{RMS})}$	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _{mb} = 25 °C	-	-	2500	V
C _{isol}	isolation capacitance	from main terminal 2 to external heatsink; f = 1 MHz; T _{mb} = 25 °C	-	10	-	pF

11. Characteristics

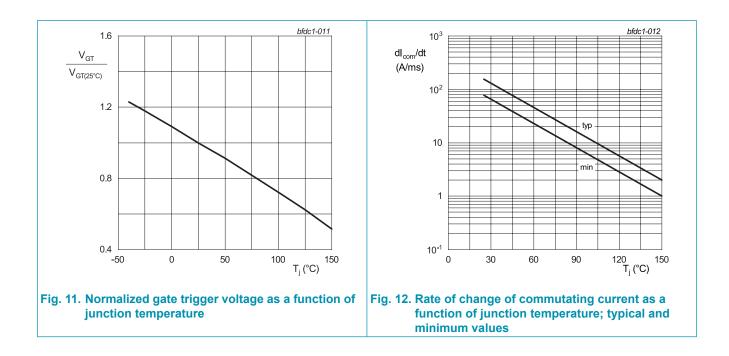
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics	,				_
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 7	-	-	35	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 7	-	-	35	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ $\text{T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 7}$	-	-	35	mA
l	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ } \text{ G+};$ $\text{T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 8}$	-	-	50	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ } \text{ G-};$ T _j = 25 °C; Fig. 8	-	-	70	mA
		V_{D} = 12 V; I_{G} = 0.1 A; T2- G-; T _j = 25 °C; Fig. 8	-	-	50	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	40	mA
V _T	on-state voltage	I _T = 10A; T _j = 25 °C; <u>Fig. 10</u>	-	1.25	1.6	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A;T _j = 25 °C Fig. 11	-	0.7	1	V
		$V_{\rm D}$ = 400V; $I_{\rm T}$ = 0.1 A; $T_{\rm j}$ = 150 °C	0.25	0.4	-	V
I _D	off-state current	$V_{\rm D}$ = 800 V; T _j = 25 °C	-	-	10	μA
		V _D = 800 V; T _j = 150 °C	-	0.3	2	mA
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536V; T_j = 125 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit	200	-	-	V/µs
		$V_{DM} = 536V; T_j = 150 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM});$ exponential waveform; gate open circuit	100	-	-	V/µs
dI _{com} /dt	rate of change of commutating current	$V_{DM} = 400 \text{ V}; \text{ T}_{\text{j}} = 150 \text{ °C}; \text{I}_{\text{T(RMS)}} = 8 \text{ A};$ $dV_{com}/dt = 20 \text{ V/}\mu\text{s}; \text{ (snubberless condition); gate open circuit}$	1	-	-	A/ms
		V_{DM} = 400 V; T _j = 150 °C;I _{T(RMS)} = 8 A; dV _{com} /dt = 10 V/µs; gate open circuit	1.5	-	-	A/ms
		V_{DM} = 400 V; T _j = 150 °C;I _{T(RMS)} = 8 A; dV _{com} /dt = 1 V/µs; gate open circuit	3	-	-	A/ms

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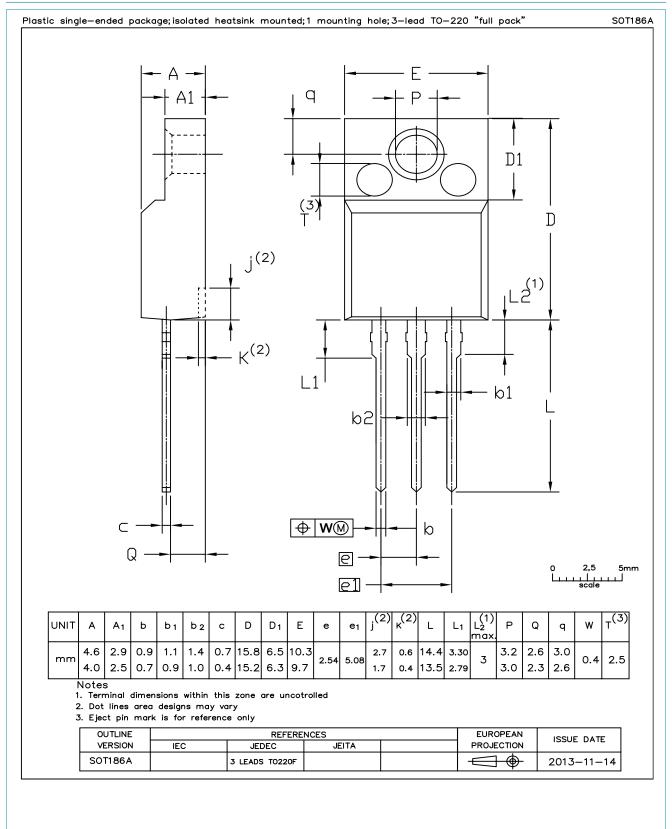


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BTA208X-800CT



12. Package outline



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13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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